

Zener Diodes

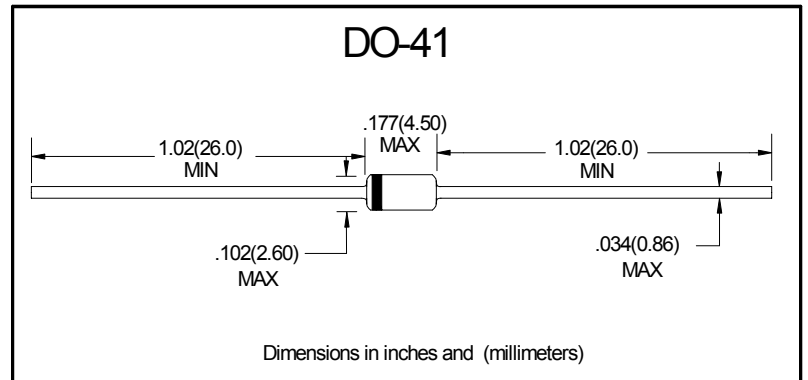
■特征 Features

- P_{tot} 1.0W
- V_z 3.3V-100V

■用途 Applications

- 稳定电压用 Stabilizing Voltage

■外形尺寸和印记 Outline Dimensions and Mark



■极限值（绝对最大额定值）

Limiting Values (Absolute Maximum Rating)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	最大值 Max
损耗功率 Power dissipation	P_{tot}	W	$L=4\text{mm}, T_L=25^\circ\text{C}$	1.0 ¹⁾
齐纳电流 Zener current	I_z	mA		P_V / V_z
最大结温 Maximum junction temperature	T_j	$^\circ\text{C}$		175
存储温度范围 Storage temperature range	T_{stg}	$^\circ\text{C}$		-65 to +175

■电特性（ $T_a=25^\circ\text{C}$ 除非另有规定）

Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

参数名称 Item	符号 Symbol	单位 Unit	条件 Conditions	最大值 Max
典型热阻(1) Thermal resistance	$R_{\theta JA}$	$^\circ\text{C}/\text{W}$	结到环境, $L=4\text{mm}$, $T_L=\text{常温}$ junction to ambient air, $L=4\text{mm}, T_L=\text{constant}$	110
正向电压 Forward voltage	V_F	V	$I_F=200\text{mA}$	1.2

备注: Notes:

¹⁾ 距离管体4毫米引线处的温度设定为环境温度

Valid provided that leads at a distance of 4 mm from case are kept at ambient temperature.

■ 电性参数 (T_A=25℃ 除非另有规定)
Electrical Characteristics (T_A=25℃ unless otherwise noted)

产品型号 Part Number	额定齐纳电压 Nominal Zener voltage ¹⁾	测试电流 Test current	最大动态电阻 Maximum dynamic impedance			最大反向漏电流 Maximum reverse leakage current		浪涌电流 Surge current ³⁾	最大调整电流 Maximum regulator current ²⁾
	V _Z at I _{ZT}	I _{ZT}	Z _{YT} at I _{ZT}	Z _{ZK} at I _{ZK}	I _{ZK}	I _R	Test voltage V _R	at T _A =25℃ I _R	I _{ZM}
	V	mA	Ω	Ω	mA	μA	V	mA	mA
1N4728A	3.3	76	10	400	1	100	1	1380	276
1N4729A	3.6	69	10	400	1	100	1	1260	252
1N4730A	3.9	64	9	400	1	50	1	1190	234
1N4731A	4.3	58	9	400	1	10	1	1070	217
1N4732A	4.7	53	8	500	1	10	1	970	193
1N4733A	5.1	49	7	550	1	10	1	890	178
1N4734A	5.6	45	5	600	1	10	2	810	162
1N4735A	6.2	41	2	700	1	10	3	730	146
1N4736A	6.8	37	3.5	700	1	10	4	660	133
1N4737A	7.5	34	4	700	0.5	10	5	605	121
1N4738A	8.2	31	4.5	700	0.5	10	6	550	110
1N4739A	9.1	28	5	700	0.5	10	7	500	100
1N4740A	10	25	7	700	0.25	10	7.6	454	91
1N4741A	11	23	8	700	0.25	5	8.4	414	83
1N4742A	12	21	9	700	0.25	5	9.1	380	76
1N4743A	13	19	10	700	0.25	5	9.9	344	69
1N4744A	15	17	14	700	0.25	5	11.4	304	61
1N4745A	16	15.5	16	700	0.25	5	12.2	285	57
1N4746A	18	14	20	750	0.25	5	13.7	250	50
1N4747A	20	12.5	22	750	0.25	5	15.2	225	45
1N4748A	22	11.5	23	750	0.25	5	16.7	205	41
1N4749A	24	10.5	25	750	0.25	5	18.2	190	38
1N4750A	27	9.5	35	750	0.25	5	20.6	170	34
1N4751A	30	8.5	40	1000	0.25	5	22.8	150	30
1N4752A	33	7.5	45	1000	0.25	5	25.1	135	27
1N4753A	36	7	50	1000	0.25	5	27.4	125	25
1N4754A	39	6.5	60	1000	0.25	5	29.7	115	23
1N4755A	43	6	70	1500	0.25	5	32.7	110	22
1N4756A	47	5.5	80	1500	0.25	5	35.8	95	19
1N4757A	51	5	95	1500	0.25	5	38.8	90	18
1N4758A	56	4.5	110	2000	0.25	5	42.6	80	16
1N4759A	62	4	125	2000	0.25	5	47.1	70	14
1N4760A	68	3.7	150	2000	0.25	5	51.7	65	13
1N4761A	75	3.3	175	2000	0.25	5	56	60	12
1N4762A	82	3.0	200	3000	0.25	5	62.2	55	11
1N4763A	91	2.8	250	3000	0.25	5	69.2	50	10
1N4764A	100	2.5	350	3000	0.25	5	76.0	45	9

备注: Notes:

¹⁾ 基于直流测试热平衡的同时保持引线的温度在30℃+1℃, 距离二极体本体距离为9.5毫米 (3/8")

Based on dc-measurement at thermal equilibrium while maintaining the lead temperature (TL) at 30℃+1℃, 9.5 mm (3/8") from the diode body

²⁾ 距离管体4毫米引线处的温度设定为环境温度

Valid provided that electrodes at a distance of 4 mm from case are kept at ambient temperature

³⁾ t_p = 10 ms

■特性曲线（典型） Characteristics(Typical)

图1：可接受功率损耗与环境温度关系

FIG1: Admissible Power Dissipation vs. Ambient Temperat

